## NSN 5961-01-117-9335

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-117-9335 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.370 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open all transistor and 60.0 breakdown voltage, collector-to-emitter, base open all transistor and 6.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.25 watts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 175.0 static forward current transfer ratio, common-emitter all transistor and 600.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a

**Fiig:** A110a0

**Unit Of Measure:** 

**Demilitarization:** Yes - demil/mli